NPN Triple Diffused Planar Silicon Transistor



2SC4461

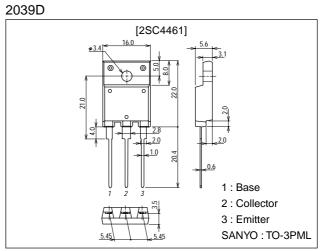
500V/25A Switching Regulator Applications

Features

- \cdot High breakdown voltage, high reliability.
- · Fast switching speed.
- · Wide ASO.
- · Adoption of MBIT process.
- · Micaless package facilitating mounting.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		800	V
Collector-to-Emitter Voltage	VCEO		500	V
Emitter-to-Base Voltage	VEBO		7	V
Collector Current	I _C		25	A
Collector Current (Pulse)	I _{CP}	PW≤300µs, duty cycle≤10%	40	A
Base Current	Ι _Β		8	A
Collector Dissipation	PC		3	W
		Tc=25°C	65	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =500V, I _E =0			10	μΑ
Emitter Cutoff Current	IEBO	$V_{EB}=5V, I_{C}=0$			10	μΑ
DC Current Gain	h _{FE} 1	$V_{CE}=5V, I_{C}=2.4A$	15*		50*	
	h _{FE} 2	V _{CE} =5V, I _C =12A	8			

* : For the hFE1 of the 2SC4461, specify two ranks or more in principle.

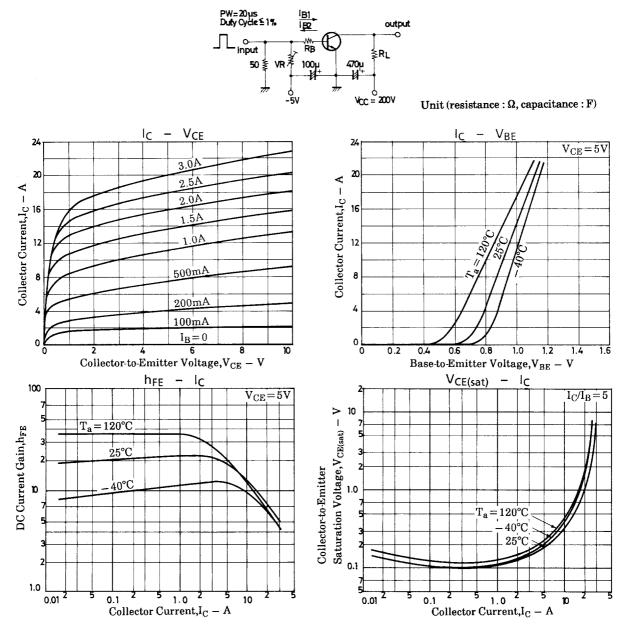
15 L 30 20 M 40 30 N 50

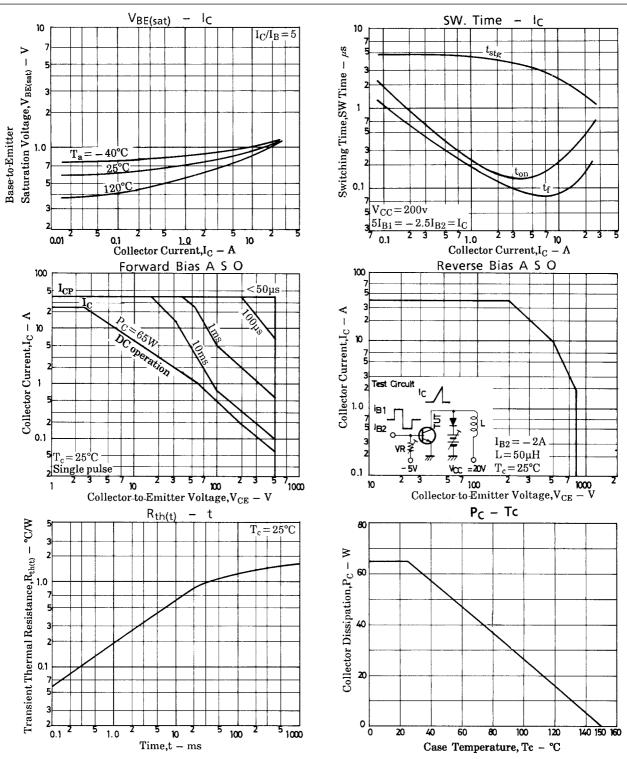
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =2.4A		18		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		260		pF
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =12A, I _B =2.4A			1.0	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =12A, I _B =2.4A			1.5	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=1mA, IE=0	800			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =5mA, R _{BE} =∞	500			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E =1mA, I _C =0	7			V
Collector-to-Emitter Sustain Voltage	V _{CEX(sus)}	I _C =10A, I _{B1} =-I _{B2} =2A, L=200µH, Clamped	500			V
Turn-ON Time	ton	V_{CC} =200V, 5I _{B1} =-2.5I _{B2} =I _C =14A, R _L =14.3Ω			0.5	μs
Storage Time	t _{stg}	V_{CC} =200V, 5I _{B1} =-2.5I _{B2} =I _C =14A, R _L =14.3Ω			3.0	μs
Fall Time	tf	V _{CC} =200V, 5I _{B1} =-2.5I _{B2} =I _C =14A, R _L =14.3Ω			0.3	μs

Switching Time Test Circuit





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